NSN 5961-00-435-6616

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Inclosure Material:
Metal
Overall Length:

0.190 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.186 inches

Internal Configuration:

Field effect

Electrode Internally-electrically Connected To Case:

Gate

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 drain to gate voltage

Current Rating Per Characteristic:

15.00 milliamperes collector current, dc

Power Rating Per Characteristic:

300.0 milliwatts collector power dissipation

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Test Data Document:

97942-579r695 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0